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Kind regards,

Team Nexperia

INTEGRATED CIRCUITS

DATA SHEET **CBTD16211** 24-bit level shifting bus exchange switch with 12-bit output enables

Product data

2001 Jun 13



CBTD16211

FEATURES

- 5Ω switch connection between two ports
- TTL compatible control input levels
- Designed to be used in level shifting applications
- Package options include shrink small outline (SSOP) and thin shrink small outline (TSSOP)
- ESD protection exceeds 1000 V CDM per JESD22-C101
- Latch-up testing is done to JESDEC Standard JESD78 which exceeds 100 mA

DESCRIPTION

The CBTD16211 provides 24 bits of high-speed TTL-compatible bus switching. The low on-state resistance of the switch allows connections to be made with minimal propagation delay.

A diode to V_{CC} is integrated in the circuit to allow for level shifting between 5 V inputs and 3.3 V outputs.

The device is organized as a dual 12-bit bus switch with separate output-enable (\overline{OE}) inputs. It can be used as two 10-bit bus switches or as one 20-bit bus switch. When \overline{OE} is low, the associated 10-bit bus switch is on, and port A is connected to port B. When \overline{OE} is high, the switch is open, and a high-impedance state exists between the ports.

The CBTD16211 is characterized for operation from –40 to +85 $^\circ$ C.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25 °C; GND = 0 V	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay An to Yn	C _L = 50 pF; V _{CC} = 5 V	0.25	ns
C _{IN}	Input capacitance	$V_I = 0 V \text{ or } V_{CC}$	4.3	pF
C _{OUT}	Output capacitance	Outputs disabled; $V_O = 0 V \text{ or } V_{CC}$	6.9	pF
I _{CC}	Total supply current	Outputs disabled; V_{CC} = 5.5 V	3.0	μΑ

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	ORDER CODE	DWG NUMBER
56-Pin Plastic SSOP Type III	–40 to +85 °C	CBTD16211DL	SOT371-1
56-Pin Plastic TSSOP Type II	–40 to +85 °C	CBTD16211DGG	SOT364-1

FUNCTION TABLE

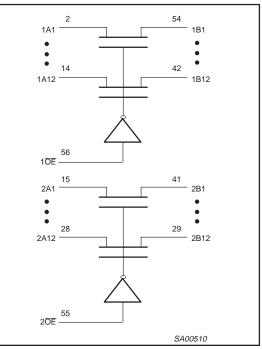
INP	JTS	OUTPUTS		
10E	2 <mark>0E</mark>	1A, 1B	2A, 2B	
L	L	1A = 1B	2A = 2B	
L	Н	1A = 1B	Z	
н	L	Z	2A = 2B	
Н	Н	Z	Z	

H = High voltage level

L = Low voltage level

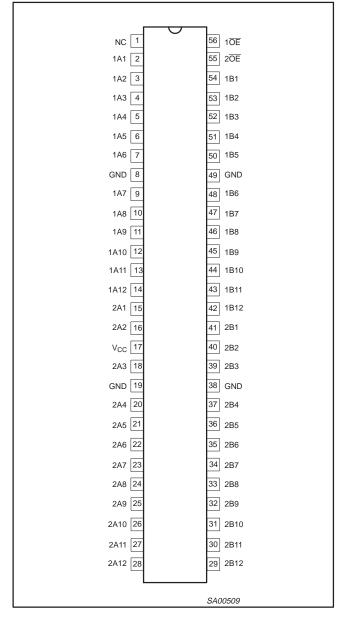
Z = High impedance "off" state

LOGIC SYMBOL



CBTD16211

PIN CONFIGURATION



PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	NC	No internal connection
56, 55	10E, 20E	Output enables
2, 3, 4, 5, 6, 7, 9, 10, 11, 12, 13, 14	1A1-1A12	Inputs
54, 53, 52, 51, 50, 48, 47, 46, 45, 44, 43, 42	1B1-1B12	Outputs
15, 16, 18, 20, 21, 22, 23, 24, 25, 26, 27, 28	2A1-2A12	Inputs
41, 40, 39, 37, 36, 35, 34, 33, 32, 31, 30, 29	2B1-2B12	Outputs
8, 19, 38, 49	GND	Ground (0 V)
17	V _{CC}	Positive supply voltage

CBTD16211

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
I _{IK}	DC input diode current	V ₁ < 0	-50	mA
VI	DC input voltage ³		-0.5 to +7.0	V
V _{OUT}	DC output voltage ³	output in Off or High state	–0.5 to +5.5	V
I _{OUT}	DC output current	output in Low state	128	mA
T _{stg}	Storage temperature range		-65 to +150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction

The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT	
	PARAMEIER	Min	Max	UNIT
V _{CC}	DC supply voltage	4.5	5.5	V
V _{IH}	High-level input voltage	2.0	_	V
V _{IL}	Low-level Input voltage	—	0.8	V
T _{amb}	Operating free-air temperature range	-40	+85	°C

DC ELECTRICAL CHARACTERISTICS

				LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS	T _{amb} = −40 to +85 °C			
			Min	Typ ¹	Max	1
V _{IK}	Input clamp voltage	$V_{CC} = 4.5 \text{ V}; I_{I} = -18 \text{ mA}$	—	—	-1.2	V
V _{OH}	Output high pass voltage	See Figure 1	—	—		V
		$V_{CC} = 0 V; V_{I} = 5.5 V$	—		10	
1	I _I Input leakage current	V_{CC} = 5.5 V; V_{I} = GND or 5.5 V	-		±1	μA
Icc	Quiescent supply current	$V_{CC} = 5.5 \text{ V}; I_O = 0, V_I = V_{CC} \text{ or GND};$ 1OE=2OE=GND	_	_	1.5	mA
ΔI_{CC}	Additional supply current per input pin ²	V_{CC} = 5.5 V, one input at 3.4 V, other inputs at V_{CC} or GND	_	-	2.5	mA
Cl	Control pins	$V_{I} = 3 V \text{ or } 0$	-	4.5	—	pF
C _{I(OFF)}	Port OFF capacitance	$V_{O} = 3 V \text{ or } 0, \overline{OE} = V_{CC}$	—	8	—	pF
		$V_{CC} = 4.5 \text{ V}; V_1 = 0 \text{ V}; I_1 = 64 \text{ mA}$	—	5	7	
r _{on} ³		$V_{CC} = 4.5 \text{ V}; V_1 = 0 \text{ V}; I_1 = 30 \text{ mA}$	—	5	7	Ω
		V _{CC} = 4.5 V; V ₁ = 2.4 V; I ₁ = -15 mA	- 1	35	50	1

NOTES:

All typical values are at V_{CC} = 5 V, T_{amb} = 25 °C. 1.

This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND. 2.

3. Measured by the voltage drop between the A and the B terminals at the indicated current through the switch.

On-state resistance is determined by the lowest voltage of the two (A or B) terminals.

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AC CHARACTERISTICS

 $GND = 0 V; t_{R;} C_L = 50 pF$

SYMBOL	PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 5.0	V ±0.5 V	UNIT
				Min	Мах	
t _{pd}	Propagation delay ¹	A or B	B or A	_	0.25	ns
t _{en}	Output enable time to High and Low level	ŌE	A or B	1.5	8.5	ns
t _{dis}	Output disable time from High and Low level	ŌĒ	A or B	1.5	7	ns

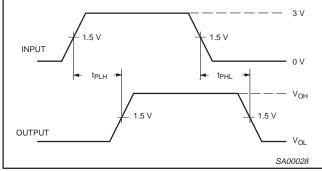
NOTE:

 This parameter is warranted but not production tested. The propagation delay is based on the RC time constant of the typical on-state resistance of the switch and a load capacitance of 50 pF, when driven by an ideal voltage source (zero output impedance).

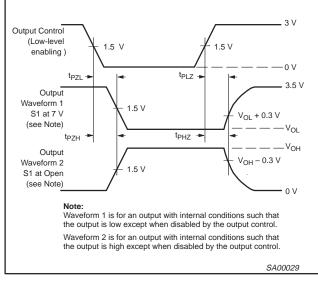
CBTD16211

AC WAVEFORMS

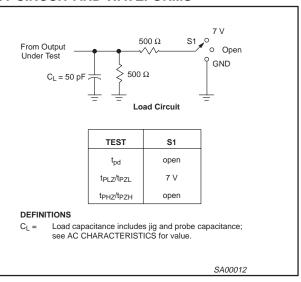
 V_{M} = 1.5 V, V_{IN} = GND to 3.0 V



Waveform 1. Input (An) to Output (Yn) Propagation Delays



Waveform 2. 3-State Output Enable and Disable Times



TEST CIRCUIT AND WAVEFORMS

TYPICAL CHARACTERISTICS

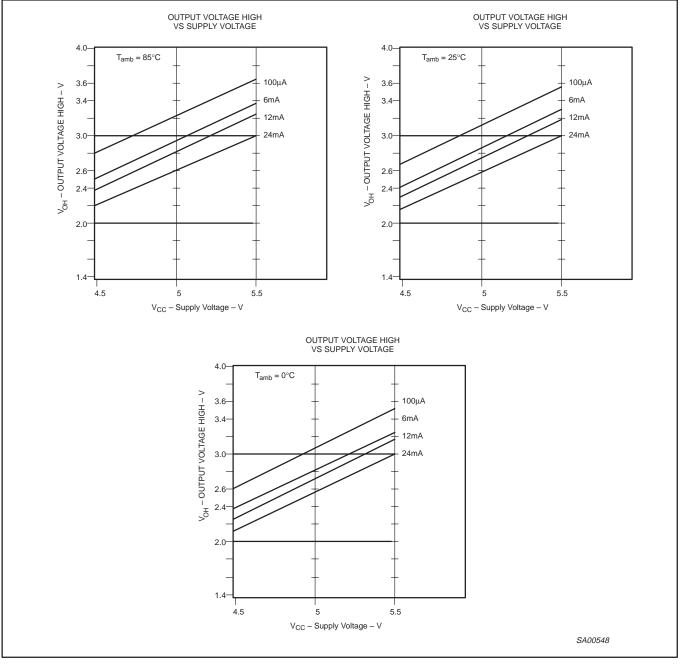
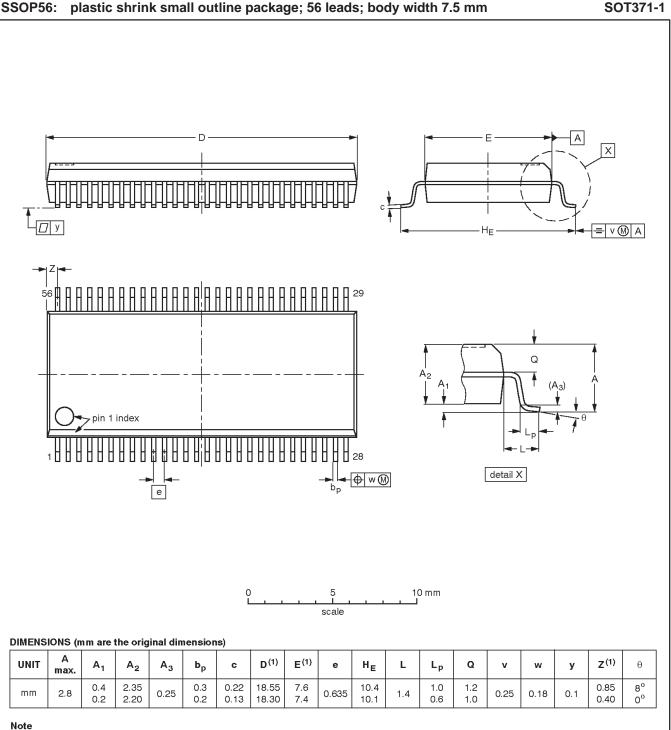


Figure 1. V_{OH} values ($V_{in} = V_{CC}$)

Product data

CBTD16211



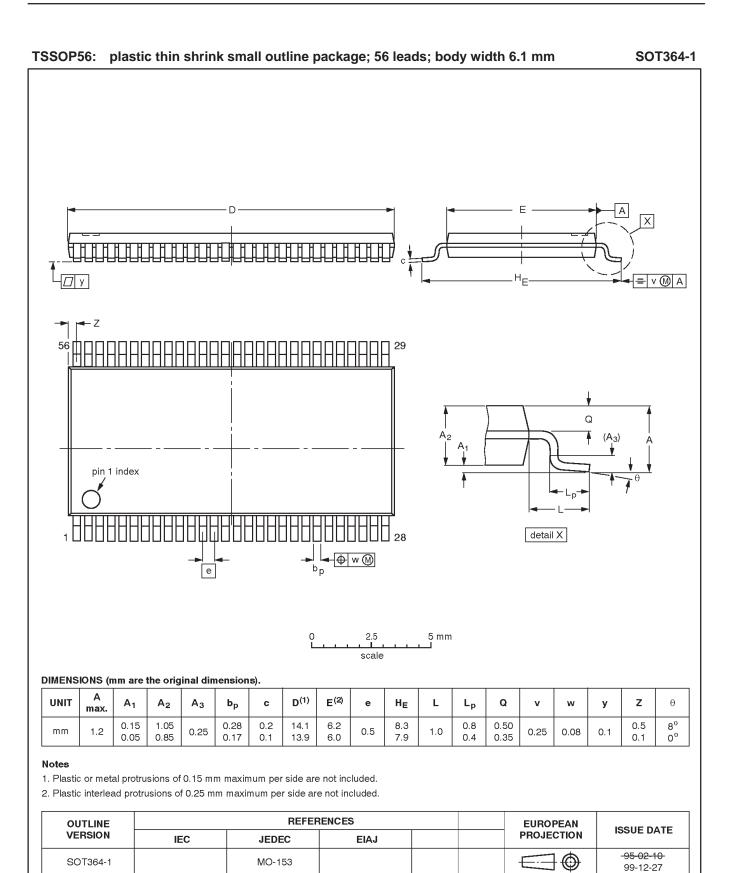
SSOP56: plastic shrink small outline package; 56 leads; body width 7.5 mm

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE	OUTLINE REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1550E DATE
SOT371-1		MO-118				-95-02-04 99-12-27

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CBTD16211



CBTD16211

Product data

Data sheet status

Data sheet status ^[1]	Product status ^[2]	Definitions
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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[1] Please consult the most recently issued datasheet before initiating or completing a design.

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